

Flux shuttling--New method for the nondestructive ream cells

IEEE Transactions on Magnetics

3, 268-271

DOI: [10.1109/tmag.1967.1066075](https://doi.org/10.1109/tmag.1967.1066075)

Citation Report

#	ARTICLE	IF	CITATIONS
1	Integrated-circuit content-addressable memories. IEEE Journal of Solid-State Circuits, 1970, 5, 208-215.	5.4	16
2	Other Random Access Systems. , 1971, , 221-240.		0
3	Computer Memory. , 1975, , 209-266.		0